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Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	768B (512 x 12)
Program Memory Type	ОТР
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c54c-04i-so

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

NOTES:

5.1 Power-On Reset (POR)

The PIC16C5X family incorporates on-chip Power-On Reset (POR) circuitry which provides an internal chip RESET for most power-up situations. To use this feature, the user merely ties the MCLR/VPP pin to VDD. A simplified block diagram of the on-chip Power-On Reset circuit is shown in Figure 5-1.

The Power-On Reset circuit and the Device Reset Timer (Section 5.2) circuit are closely related. On power-up, the RESET latch is set and the DRT is <u>RESET</u>. The DRT timer begins counting once it detects MCLR to be high. After the time-out period, which is typically 18 ms, it will RESET the reset latch and thus end the on-chip RESET signal.

A power-up example where MCLR is not tied to VDD is shown in Figure 5-3. VDD is allowed to rise and stabilize before bringing MCLR high. The chip will actually come out of reset TDRT msec after MCLR goes high.

In Figure 5-4, the on-chip Power-On Reset feature is being used (MCLR and VDD are tied together). The VDD is stable before the start-up timer times out and there is no problem in getting a proper RESET. However, Figure 5-5 depicts a problem situation where VDD rises too slowly. The time between when the DRT senses a high on the MCLR/VPP pin, and when the MCLR/VPP pin (and VDD) actually reach their full value, is too long. In this situation, when the start-up timer times out, VDD has not reached the VDD (min) value and the chip is, therefore, not guaranteed to function correctly. For such situations, we recommend that external RC circuits be used to achieve longer POR delay times (Figure 5-2).

Note: When the device starts normal operation (exits the RESET condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in RESET until the operating conditions are met.

For more information on PIC16C5X POR, see *Power-Up Considerations* - AN522 in the <u>Embedded Control Handbook</u>.

The POR circuit does not produce an internal RESET when VDD declines.

FIGURE 5-2:

EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



- External Power-On Reset circuit is required only if VDD power-up is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.
- R < 40 kΩ is recommended to make sure that voltage drop across R does not violate the device electrical specification.
- R1 = 100Ω to 1 k Ω will limit any current flowing into \overline{MCLR} from external capacitor C in the event of \overline{MCLR} pin breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

9.2 Watchdog Timer (WDT)

The Watchdog Timer (WDT) is a free running on-chip RC oscillator which does not require any external components. This RC oscillator is separate from the RC oscillator of the OSC1/CLKIN pin. That means that the WDT will run even if the clock on the OSC1/CLKIN and OSC2/CLKOUT pins have been stopped, for example, by execution of a SLEEP instruction. During normal operation or SLEEP, a WDT Reset or Wake-up Reset generates a device RESET.

The $\overline{\text{TO}}$ bit (STATUS<4>) will be cleared upon a Watchdog Timer Reset (Section 6.3).

The WDT can be permanently disabled by programming the configuration bit WDTE as a '0' (Section 9.1). Refer to the PIC16C5X Programming Specifications (Literature Number DS30190) to determine how to access the configuration word.

9.2.1 WDT PERIOD

An 8-bit counter is available as a prescaler for the Timer0 module (Section 8.2), or as a postscaler for the Watchdog Timer (WDT), respectively. For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not

both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio (Section 6.4).

The WDT has a nominal time-out period of 18 ms (with no prescaler). If a longer time-out period is desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT (under software control) by writing to the OPTION register. Thus, time-out a period of a nominal 2.3 seconds can be realized. These periods vary with temperature, VDD and part-to-part process variations (see Device Characterization).

Under worst case conditions (VDD = Min., Temperature = Max., WDT prescaler = 1:128), it may take several seconds before a WDT time-out occurs.

9.2.2 WDT PROGRAMMING CONSIDERATIONS

The CLRWDT instruction clears the WDT and the prescaler, if assigned to the WDT, and prevents it from timing out and generating a device RESET.

The SLEEP instruction RESETS the WDT and the prescaler, if assigned to the WDT. This gives the maximum SLEEP time before a WDT Wake-up Reset.

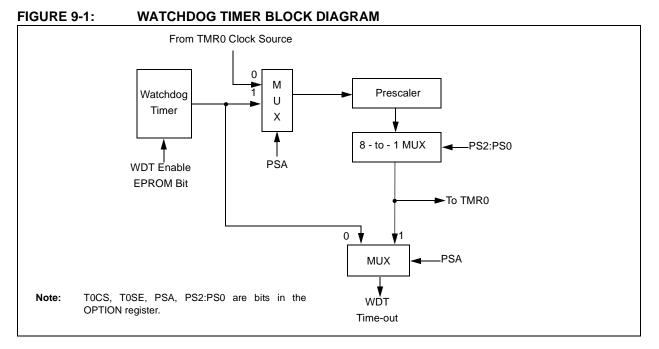


TABLE 9-1: SUMMARY OF REGISTERS ASSOCIATED WITH THE WATCHDOG TIMER

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-On Reset	<u>Value</u> on MCLR and WDT Reset
N/A	OPTION	—		Tosc	Tose	PSA	PS2	PS1	PS0	11 1111	11 1111

Legend: u = unchanged, - = unimplemented, read as '0'. Shaded cells not used by Watchdog Timer.

10.0 INSTRUCTION SET SUMMARY

Each PIC16C5X instruction is a 12-bit word divided into an OPCODE, which specifies the instruction type and one or more operands which further specify the operation of the instruction. The PIC16C5X instruction set summary in Table 10-2 groups the instructions into byte-oriented, bit-oriented, and literal and control operations. Table 10-1 shows the opcode field descriptions.

For **byte-oriented** instructions, 'f' represents a file register designator and 'd' represents a destination designator. The file register designator is used to specify which one of the 32 file registers in that bank is to be used by the instruction.

The destination designator specifies where the result of the operation is to be placed. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed in the file register specified in the instruction.

For **bit-oriented** instructions, 'b' represents a bit field designator which selects the number of the bit affected by the operation, while 'f' represents the number of the file in which the bit is located.

For **literal and control** operations, 'k' represents an 8 or 9-bit constant or literal value.

TABLE 10-1:	OPCODE FIELD
	DESCRIPTIONS

DESCRIPTIONS							
Field	Description						
f	Register file address (0x00 to 0x1F)						
W	Working register (accumulator)						
b	Bit address within an 8-bit file register						
k	Literal field, constant data or label						
x	Don't care location (= 0 or 1) The assembler will generate code with $x = 0$. It is the recommended form of use for com-						
	patibility with all Microchip software tools.						
d	Destination select; d = 0 (store result in W) d = 1 (store result in file register 'f') Default is d = 1						
label	Label name						
TOS	Top of Stack						
PC	Program Counter						
WDT	Watchdog Timer Counter						
TO	Time-out bit						
PD	Power-down bit						
dest	Destination, either the W register or the specified register file location						
[]	Options						
()	Contents						
\rightarrow	Assigned to						
< >	Register bit field						
∈	In the set of						
italics	User defined term (font is courier)						

All instructions are executed within one single instruction cycle, unless a conditional test is true or the program counter is changed as a result of an instruction. In this case, the execution takes two instruction cycles. One instruction cycle consists of four oscillator periods. Thus, for an oscillator frequency of 4 MHz, the normal instruction execution time would be 1 μ s. If a conditional test is true or the program counter is changed as a result of an instruction, the instruction execution time would be 2 μ s.

Figure 10-1 shows the three general formats that the instructions can have. All examples in the figure use the following format to represent a hexadecimal number:

0xhhh

where 'h' signifies a hexadecimal digit.

FIGURE 10-1: GENERAL FORMAT FOR INSTRUCTIONS

Byte-oriented file register operations									
<u>11 6</u>	5	4 0							
OPCODE	d	f (FILE #)							
d = 1 for destination	d = 0 for destination W d = 1 for destination f f = 5-bit file register address								
Bit-oriented file registe	r ope	erations							
11 8	7	5 4 0							
OPCODE	b (Bl	IT #) f (FILE #)							
Literal and control ope	 b = 3-bit bit address f = 5-bit file register address Literal and control operations (except GOTO) 								
11	8	7 0							
OPCODE		k (literal)							
k = 8-bit immedia	k = 8-bit immediate value								
Literal and control operations - GOTO instruction									
11	9	8 0							
OPCODE		k (literal)							
k = 9-bit immediate value									

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PIC16C5X

RLF	Rotate Left f through Carry									
Syntax:	[<i>label</i>] RLF f,d									
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$									
Operation:	See description below									
Status Affected:	С									
Encoding:	0011 01df ffff									
Description:	The contents of register 'f' are rotated one bit to the left through the Carry Flag (STATUS<0>). If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is stored back in register 'f'.									
Words:	1									
Cycles:	1									
Example:	RLF REG1,0									
Before Instru REG1 C After Instruct	= 1110 0110 = 0 tion									
REG1 W C	= 1110 0110 = 1100 1100 = 1									

RRF	Rotate Right f through Carry									
Syntax:	[<i>label</i>] RRF f,d									
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$									
Operation:	See description below									
Status Affected:	С									
Encoding:	0011 00df ffff									
Description:	The contents of register 'f' are rotated one bit to the right through the Carry Flag (STATUS<0>). If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.									
Words:	1									
Cycles:	1									
Example:	RRF REG1,0									
Before Instru REG1 C After Instruct	$= 1110 0110 \\ = 0$									
REG1 W C	= 1110 0110 = 0111 0011 = 0									

SLEEP	Enter SLEEP Mode								
Syntax:	[<i>label</i>] SLEEP								
Operands:	None								
Operation:	00h \rightarrow WDT; 0 \rightarrow WDT prescaler; if assigned 1 \rightarrow TO; 0 \rightarrow PD								
Status Affected:	TO, PD								
Encoding:	0000 0000 0011								
Description:	Time-out status bit (\overline{TO}) is set. The power-down status bit (\overline{PD}) is cleared. The WDT and its pres- caler are cleared. The processor is put into SLEEP mode with the oscillator stopped. See section on SLEEP for more details.								
Words:	1								
Cycles:	1								
Example:	SLEEP								

12.5 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

DC CHARACTERISTICS		Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage						
		I/O ports	Vss	—	0.15 Vdd	V	Pin at hi-impedance	
		MCLR (Schmitt Trigger)	Vss	—	0.15 Vdd	V	-	
		T0CKI (Schmitt Trigger)	Vss	_	0.15 VDD	V		
		OSC1 (Schmitt Trigger)	Vss	_	0.15 VDD	V	PIC16C5X-RC only ⁽³⁾	
		OSC1 (Schmitt Trigger)	Vss	—	0.3 Vdd	V	PIC16C5X-XT, 10, HS, LP	
D040	Vih	Input High Voltage						
		I/O ports	0.45 Vdd		Vdd	V	For all VDD ⁽⁴⁾	
		I/O ports	2.0	—	Vdd	V	$4.0V < VDD \le 5.5V^{(4)}$	
		I/O ports	0.36 VDD	—	Vdd	V	VDD > 5.5 V	
		MCLR (Schmitt Trigger)	0.85 Vdd	_	Vdd	V		
		T0CKI (Schmitt Trigger)	0.85 Vdd	_	Vdd	V		
		OSC1 (Schmitt Trigger)	0.85 Vdd	_	Vdd	V	PIC16C5X-RC only ⁽³⁾	
		OSC1 (Schmitt Trigger)	0.7 Vdd	—	Vdd	V	PIC16C5X-XT, 10, HS, LP	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	_	—	V		
D060	lı∟	Input Leakage Current (1,2)					For V DD ≤ 5.5 V :	
		I/O ports	-1	0.5	+1	μA	VSS \leq VPIN \leq VDD, pin at hi-impedance	
		MCLR	-5	_	_	μA	VPIN = VSS + 0.25V	
		MCLR	_	0.5	+5	μA	VPIN = VDD	
		тоскі	-3	0.5	+3	μA	$VSS \leq VPIN \leq VDD$	
		OSC1	-3	0.5	+3	μA	$VSS \le VPIN \le VDD$, PIC16C5X-XT, 10, HS, LP	
D080	Vol	Output Low Voltage						
		I/O ports OSC2/CLKOUT	—	_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC	
D090	Vон	Output High Voltage⁽²⁾ I/O ports OSC2/CLKOUT	Vdd – 0.7 Vdd – 0.7			V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC	

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

2: Negative current is defined as coming out of the pin.

3: For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.

13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)				$\begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$						
PIC16CR54A-04, 10, 20 PIC16CR54A-04I, 10I, 20I (Commercial, Industrial)			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$							
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions			
	IPD	Power-down Current ⁽²⁾								
D006		PIC16LCR54A-Commercial		1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled			
D006A		PIC16CR54A-Commercial		1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled			
D007		PIC16LCR54A-Industrial		1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled			
D007A		PIC16CR54A-Industrial		1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled			

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

13.3 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

DC CH	DC CHARACTERISTICS			$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array} $					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD	V V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes		
D040	VIн	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.6 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.85 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V	VDD = 3.0V to 5.5V ⁽⁴⁾ Full VDD range ⁽⁴⁾ RC mode only ⁽³⁾ XT, HS and LP modes		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	—	—	V			
D060	lι∟	Input Leakage Current ^(1,2) I/O ports	-1.0	_	+1.0	μA	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance		
		MCLR MCLR TOCKI OSC1	-5.0 -3.0 -3.0	— 0.5 0.5 0.5	 +5.0 +3.0 +3.0	μΑ μΑ μΑ	$\label{eq:VPIN} \begin{array}{l} VPIN = VSS + 0.25V \\ VPIN = VDD \\ VSS \leq VPIN \leq VDD \\ VSS \leq VPIN \leq VDD, \\ XT, HS \text{and} LP \text{modes} \end{array}$		
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.5 0.5	V V	IOL = 10 mA, $VDD = 6.0VIOL = 1.9$ mA, $VDD = 6.0V$, RC mode only		
D090	Vон	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.5 Vdd - 0.5	_		V V	IOH = -4.0 mA, VDD = 6.0 V IOH = -0.8 mA, VDD = 6.0 V, RC mode only		

* These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - 2: Negative current is defined as coming out of the pin.
 - **3:** For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
 - 4: The user may use the better of the two specifications.

FIGURE 14-9: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS vs. VDD







15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial) PIC16C54A-04I, 10I, 20I (Industrial) PIC16LC54A-04 (Commercial) PIC16LC54A-04I (Industrial)

PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)				$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$						
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions		
	IPD	Power-down Current ⁽²⁾							
D006		PIC16LC5X		2.5 0.25 2.5 0.25	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT enabled, Commercial VDD = 2.5V, WDT disabled, Commercial VDD = 2.5V, WDT enabled, Industrial VDD = 2.5V, WDT disabled, Industrial		
D006A		PIC16C5X		4.0 0.25 5.0 0.3	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT enabled, Commercial VDD = 3.0V, WDT disabled, Commercial VDD = 3.0V, WDT enabled, Industrial VDD = 3.0V, WDT disabled, Industrial		

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

15.3 DC Characteristics: PIC16LV54A-02 (Commercial) PIC16LV54A-02I (Industrial)

PIC16LV54A-02 PIC16LV54A-02I (Commercial, Industrial)				$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -20^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
D001	Vdd	Supply Voltage RC and XT modes	2.0	_	3.8	V			
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	—	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset		
D004	Svdd	VDD Rise Rate to ensure Power-on Reset	0.05*	_	—	V/ms	See Section 5.1 for details on Power-on Reset		
D010	IDD	Supply Current⁽²⁾ RC ⁽³⁾ and XT modes LP mode, Commercial LP mode, Industrial		0.5 11 14	 27 35	mA μA μA	Fosc = 2.0 MHz, VDD = 3.0V Fosc = 32 kHz, VDD = 2.5V WDT disabled Fosc = 32 kHz, VDD = 2.5V WDT disabled		
D020	IPD	Power-down Current^(2,4) Commercial Commercial Industrial Industrial		2.5 0.25 3.5 0.3	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled		

These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.
 - 4: The oscillator start-up time can be as much as 8 seconds for XT and LP oscillator selection on wake-up from SLEEP mode or during initial power-up.

15.5 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

S						
Frequency	T Time					
Lowercase letters (pp) and their meanings:						
0	mc MCLR					
CLKOUT	osc oscillator					
cycle time	os OSC1					
device reset timer	t0 T0CKI					
I/O port	wdt watchdog timer					
case letters and their meanings:						
Fall	P Period					
High	R Rise					
Invalid (Hi-impedance)	V Valid					
Low	Z Hi-impedance					
	case letters (pp) and their meanings: o CLKOUT cycle time device reset timer /O port case letters and their meanings: Fall High Invalid (Hi-impedance)					

FIGURE 15-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54A

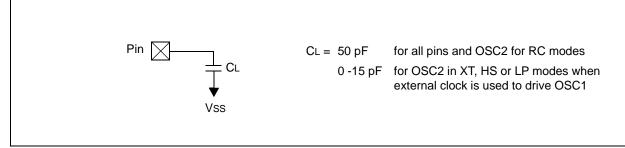




FIGURE 16-17: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD



17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
PIC16C5X PIC16CR5X (Commercial, Industrial)			Operating Temperature				ions (unless otherwise specified) 0°C ≤ TA ≤ +70°C for commercial −40°C ≤ TA ≤ +85°C for industrial		
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units			Units	Conditions		
	Vdd	Supply Voltage							
D001		PIC16LC5X	2.5 2.7 2.5		5.5 5.5 5.5	V V V	$\begin{array}{l} -40^{\circ}C \leq TA \leq +\ 85^{\circ}C,\ 16LCR5X \\ -40^{\circ}C \leq TA \leq 0^{\circ}C,\ 16LC5X \\ 0^{\circ}C \leq TA \leq +\ 85^{\circ}C\ 16LC5X \end{array}$		
D001A		PIC16C5X	3.0 4.5	_	5.5 5.5	V V	RC, XT, LP and HS mode from 0 - 10 MHz from 10 - 20 MHz		
D002	Vdr	RAM Data Retention Volt- age ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset		

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)				$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array} $					
PIC16C5X PIC16CR5X (Commercial, Industrial)				$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specif} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for comme} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industr} \end{array}$					
Param No.	Symbol Characteristic/Device			Тур†	Max	Units	Conditions		
	IPD	Power-down Current ⁽²⁾							
D020		PIC16LC5X		0.25 0.25 1 1.25	2 3 5 8	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled, Commercial $VDD = 2.5V$, WDT disabled, Industrial $VDD = 2.5V$, WDT enabled, Commercial $VDD = 2.5V$, WDT enabled, Industrial		
D020A		PIC16C5X		0.25 0.25 1.8 2.0 4 4 9.8 12	4.0 5.0 7.0* 8.0* 12* 14* 27* 30*	μΑ μΑ μΑ μΑ μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT disabled, Commercial VDD = 3.0V, WDT disabled, Industrial VDD = 5.5V, WDT disabled, Industrial VDD = 5.5V, WDT disabled, Industrial VDD = 3.0V, WDT enabled, Commercial VDD = 3.0V, WDT enabled, Industrial VDD = 5.5V, WDT enabled, Commercial VDD = 5.5V, WDT enabled, Industrial		

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .



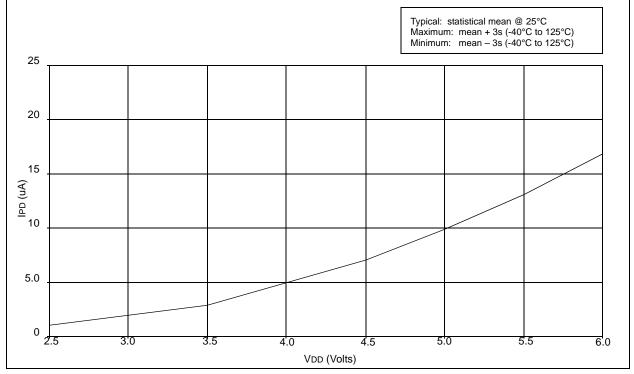
FIGURE 18-4: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 300 PF, 25°C



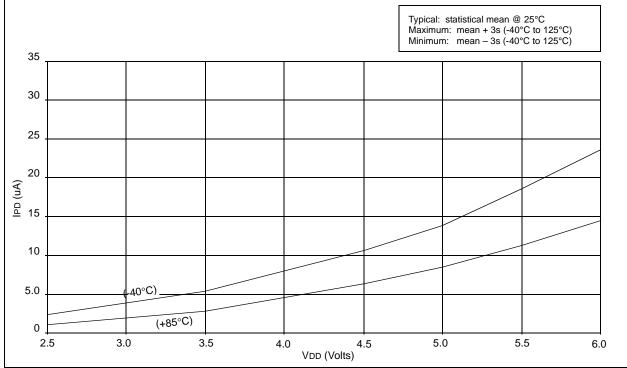


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19.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

			Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O Ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	Vss Vss Vss Vss		0.8 0.15 VDD 0.15 VDD 0.2 VDD	> > > >	4.5V <vdd <math="">\leq 5.5V HS, 20 MHz \leq Fosc \leq 40 MHz</vdd>	
D040	Viн	Input High Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	2.0 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.8 Vdd		Vdd Vdd Vdd Vdd	V V V V	$4.5V < VDD \le 5.5V$ HS, 20 MHz \le Fosc \le 40 MHz	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	_	V		
D060	lı∟	Input Leakage Current ^(2,3) I/O ports MCLR MCLR T0CKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, HS	
D080	Vol	Output Low Voltage I/O ports		_	0.6	V	Iol = 8.7 mA, Vdd = 4.5V	
D090	Vон	Output High Voltage⁽³⁾ I/O ports	Vdd - 0.7	_	_	V	Іон = -5.4 mA, Vdd = 4.5V	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected and HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 17.3.

2: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

3: Negative current is defined as coming out of the pin.

19.3 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	2. TppS						
Т							
F	Frequency	T Time					
Lowe	ercase letters (pp) and their meanings:						
рр							
2	to	mc MCLR					
ck	CLKOUT	osc oscillator					
су	cycle time	os OSC1					
drt	device reset timer	t0 T0CKI					
io	I/O port	wdt watchdog timer					
Uppe	ercase letters and their meanings:						
S							
F	Fall	P Period					
н	High	R Rise					
Ι	Invalid (Hi-impedance)	V Valid					
L	Low	Z Hi-impedance					

FIGURE 19-2: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/C55A/C56A/C57C/C58B-40

